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(12) **United States Design Patent**
Miyoshi

(10) **Patent No.:** **US D677,229 S**
(45) **Date of Patent:** **** Mar. 5, 2013**

- (54) **LIGHT EMITTING DIODE**
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- (73) Assignee: **Nichia Corporation** (JP)
- (**) Term: **14 Years**
- (21) Appl. No.: **29/418,151**
- (22) Filed: **Apr. 12, 2012**

Related U.S. Application Data

- (62) Division of application No. 29/362,717, filed on May 28, 2010, now Pat. No. Des. 660,811.

(30) **Foreign Application Priority Data**

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- Nov. 30, 2009 (JP) 2009-027809

- (51) **LOC (9) Cl.** **13-03**
 - (52) **U.S. Cl.** **D13/180**
 - (58) **Field of Classification Search** D13/180;
D26/1, 2; 257/79, 80, 81, 88, 89, 95, 98,
257/99, 100, E33.058; 313/483, 498, 500;
362/555, 800
- See application file for complete search history.

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(57) **CLAIM**

The ornamental design for a light emitting diode, as shown and described.

DESCRIPTION

FIG. 1 is a front, bottom, right side perspective view of a first embodiment of a light emitting diode showing my new design;

FIG. 2 is a front elevational view thereof;

FIG. 3 is a rear elevational view thereof;

FIG. 4 is a top plan view thereof;

FIG. 5 is a bottom plan view thereof;

FIG. 6 is a left side elevational view thereof, the right side view being a mirror image thereof;

FIG. 7 is a front, bottom, right side perspective view of a second embodiment of a light emitting diode showing my new design;

FIG. 8 is a front elevational view thereof;

FIG. 9 is a rear elevational view thereof;

FIG. 10 is a top plan view thereof;

FIG. 11 is a bottom plan view thereof; and,

FIG. 12 is a left side elevational view thereof, the right side view being a mirror image thereof.

The embodiments illustrate two L-shaped electrodes. The electrodes are made by plating onto the substrate and are thus very thin. As a result, they do not appear in the top, bottom, left side and right side views.

The broken lines are for the purpose of illustrating portions of the light emitting diode and form no part of the claimed design.

1 Claim, 10 Drawing Sheets

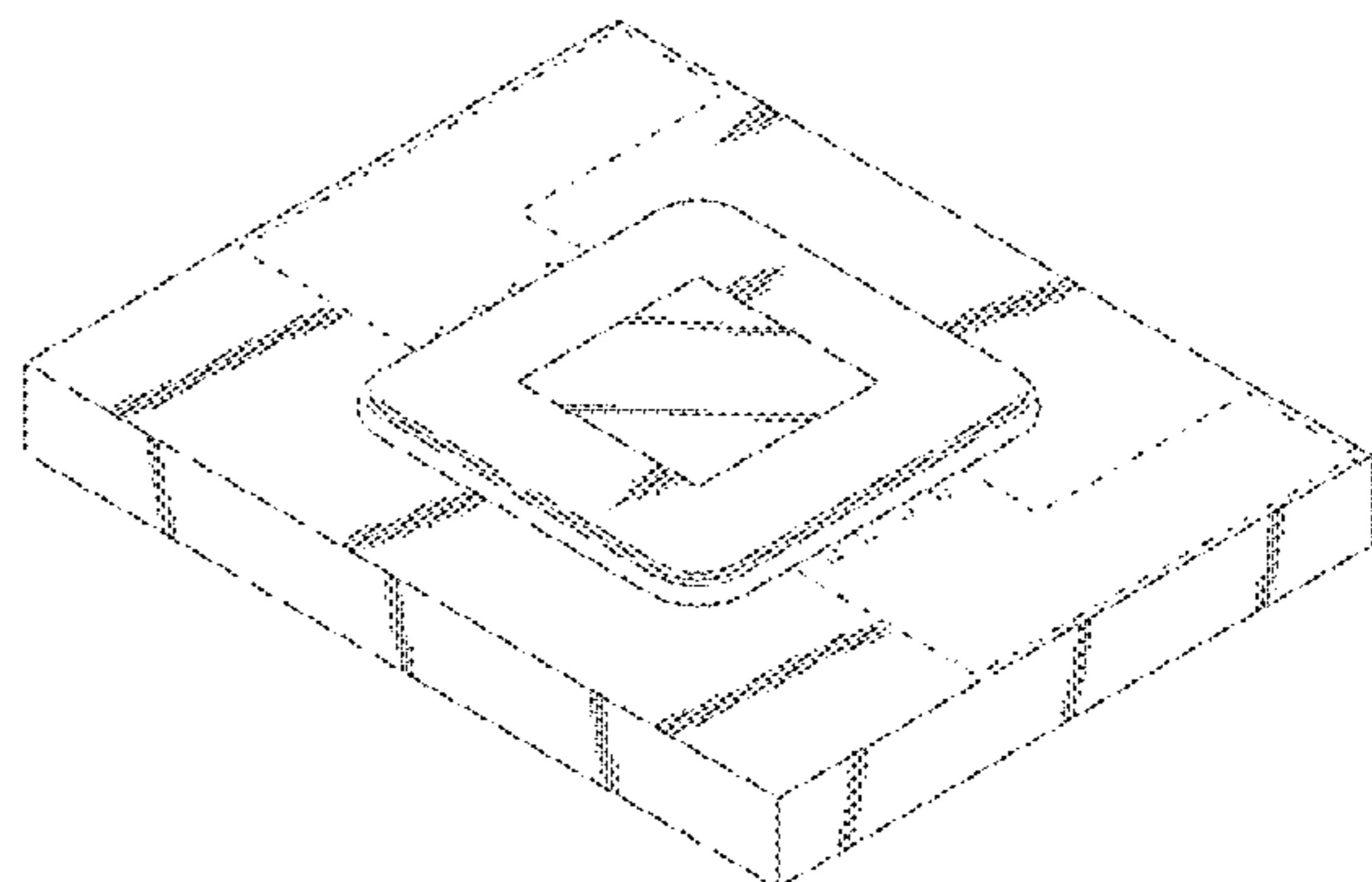
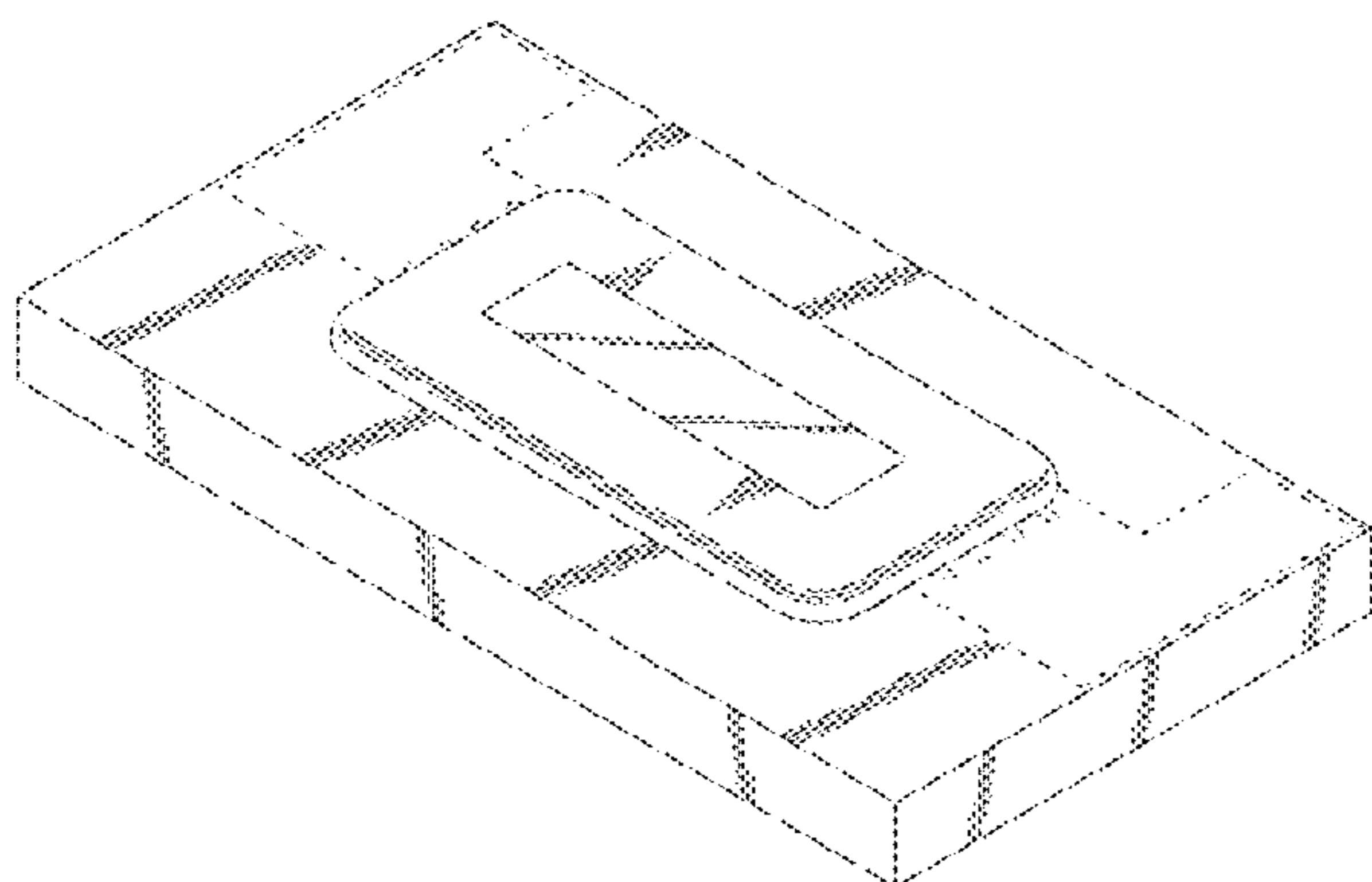


FIG. 1

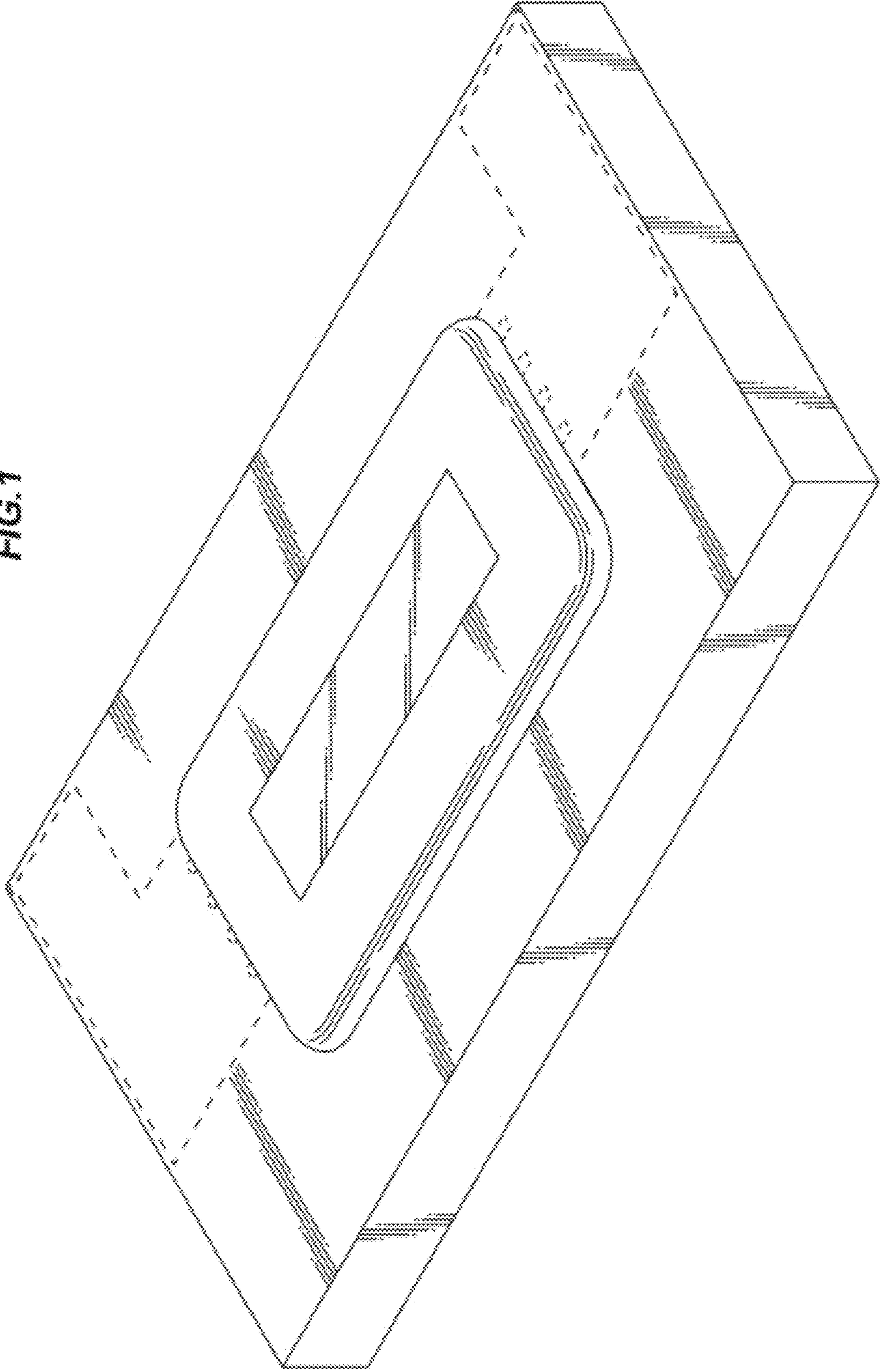


FIG.2

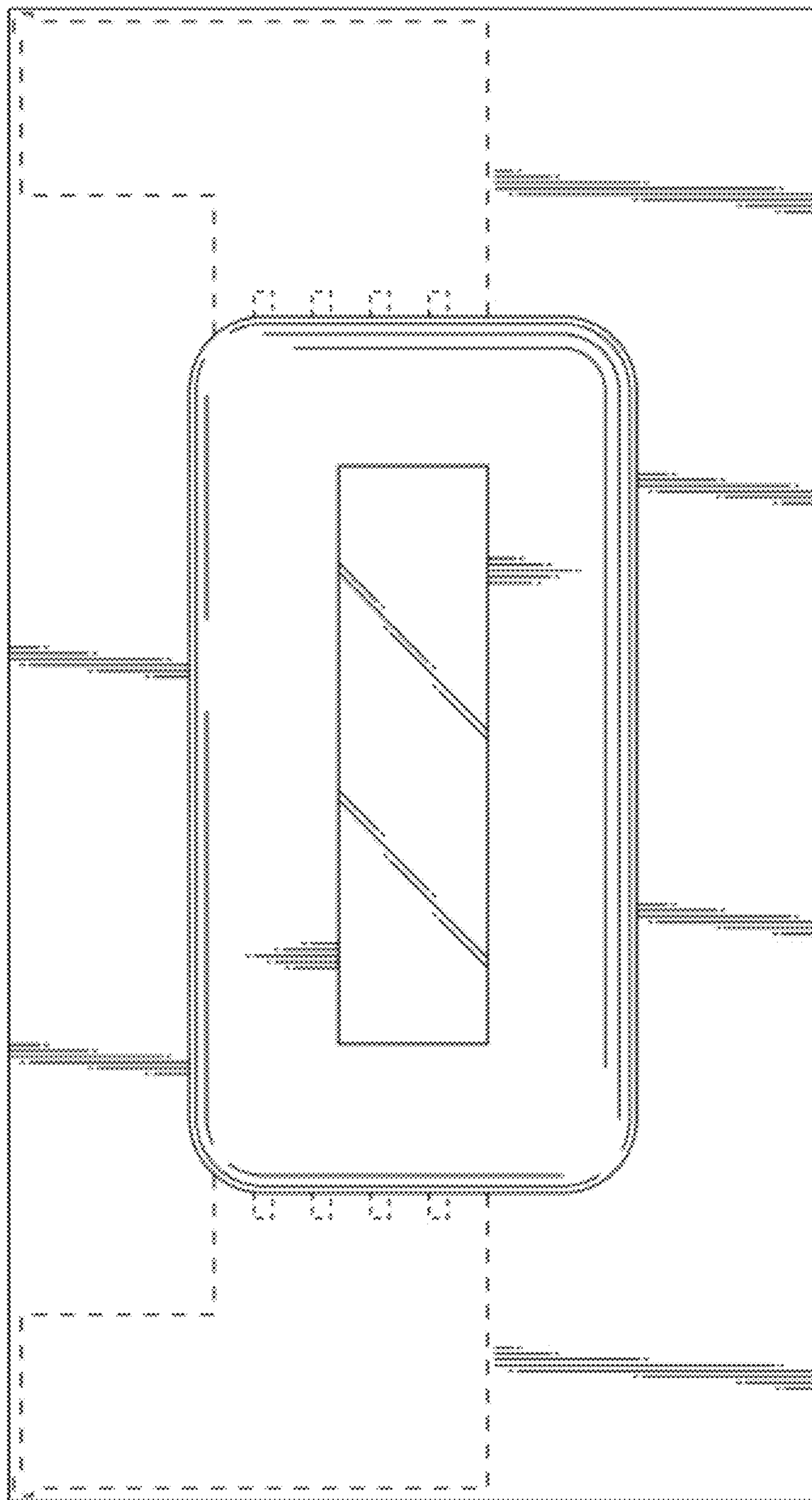


FIG. 3

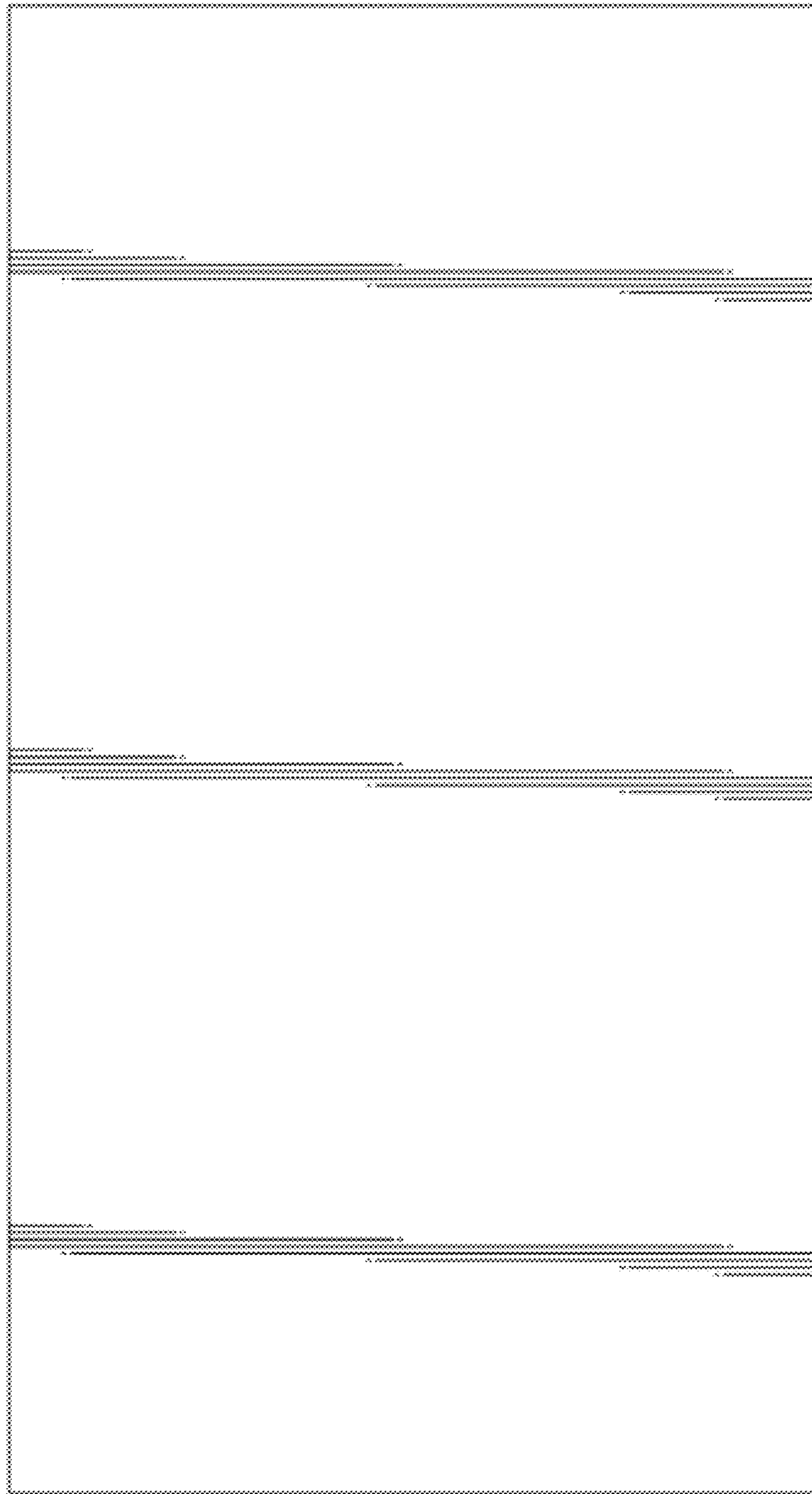


FIG.4

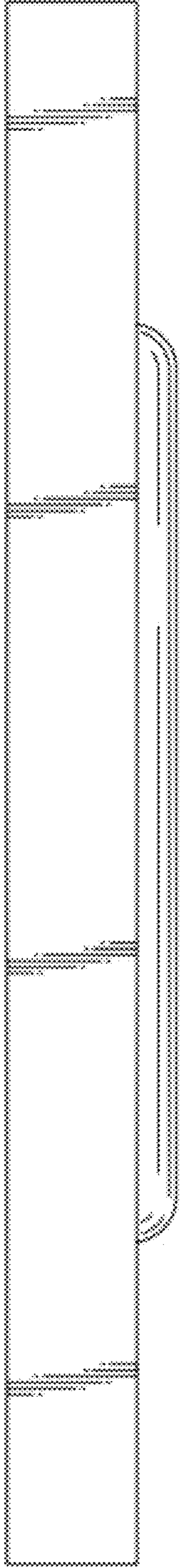


FIG.5

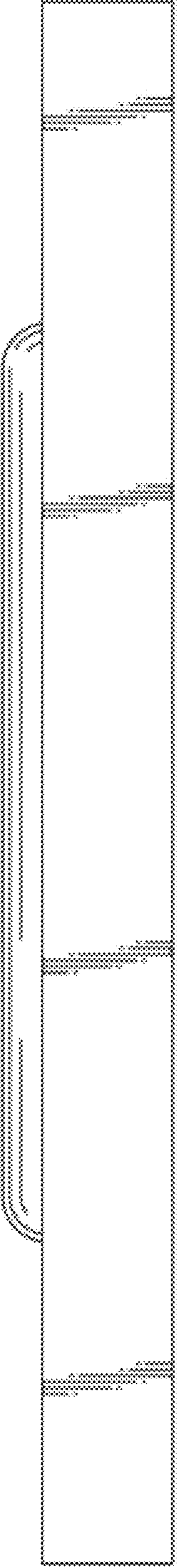


FIG. 6

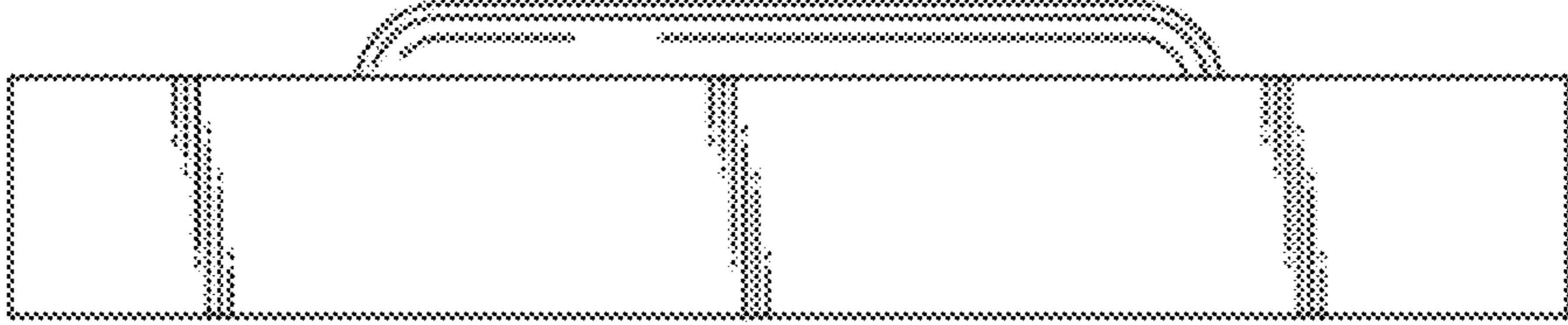


FIG. 7

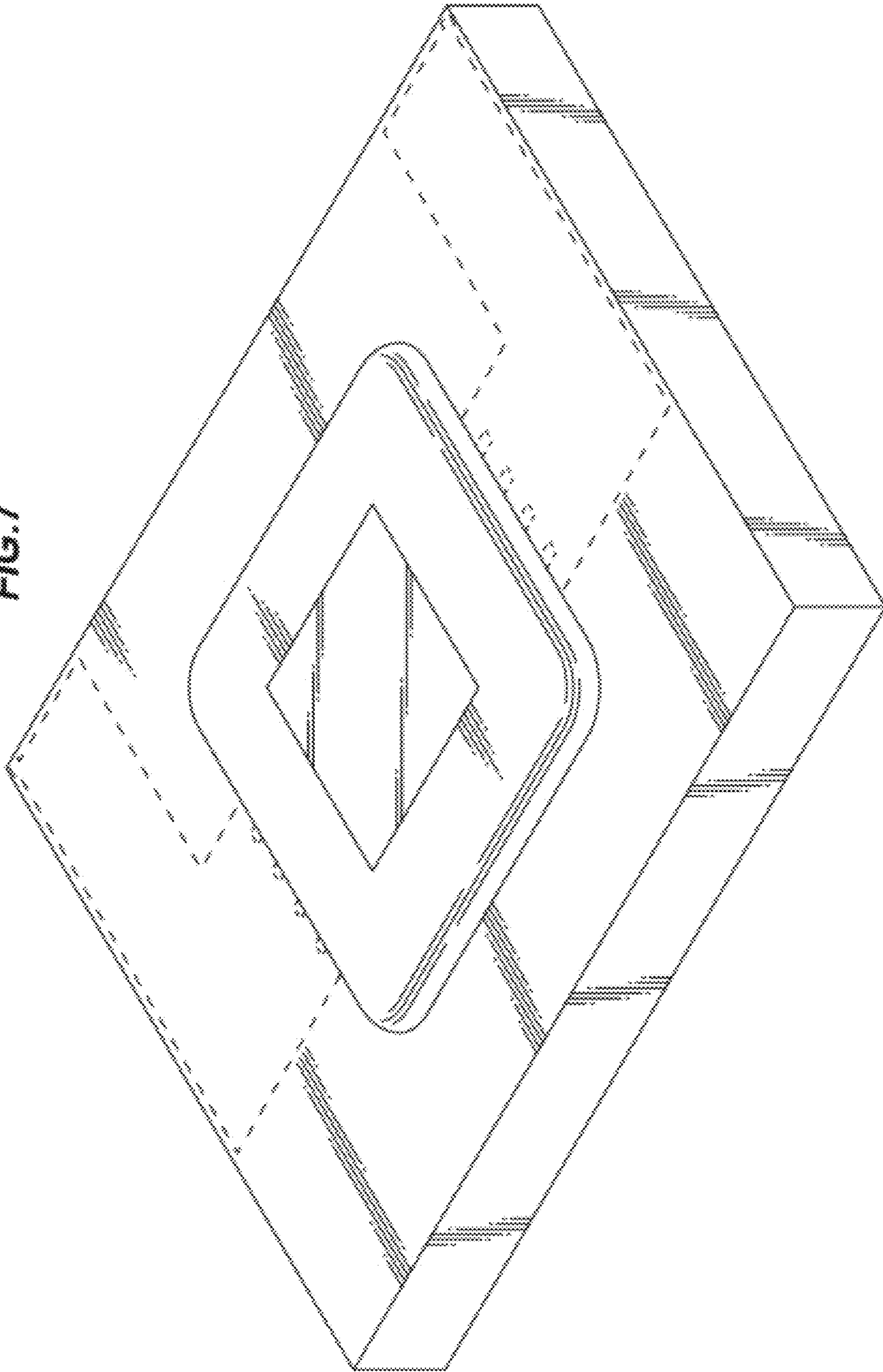


FIG. 8

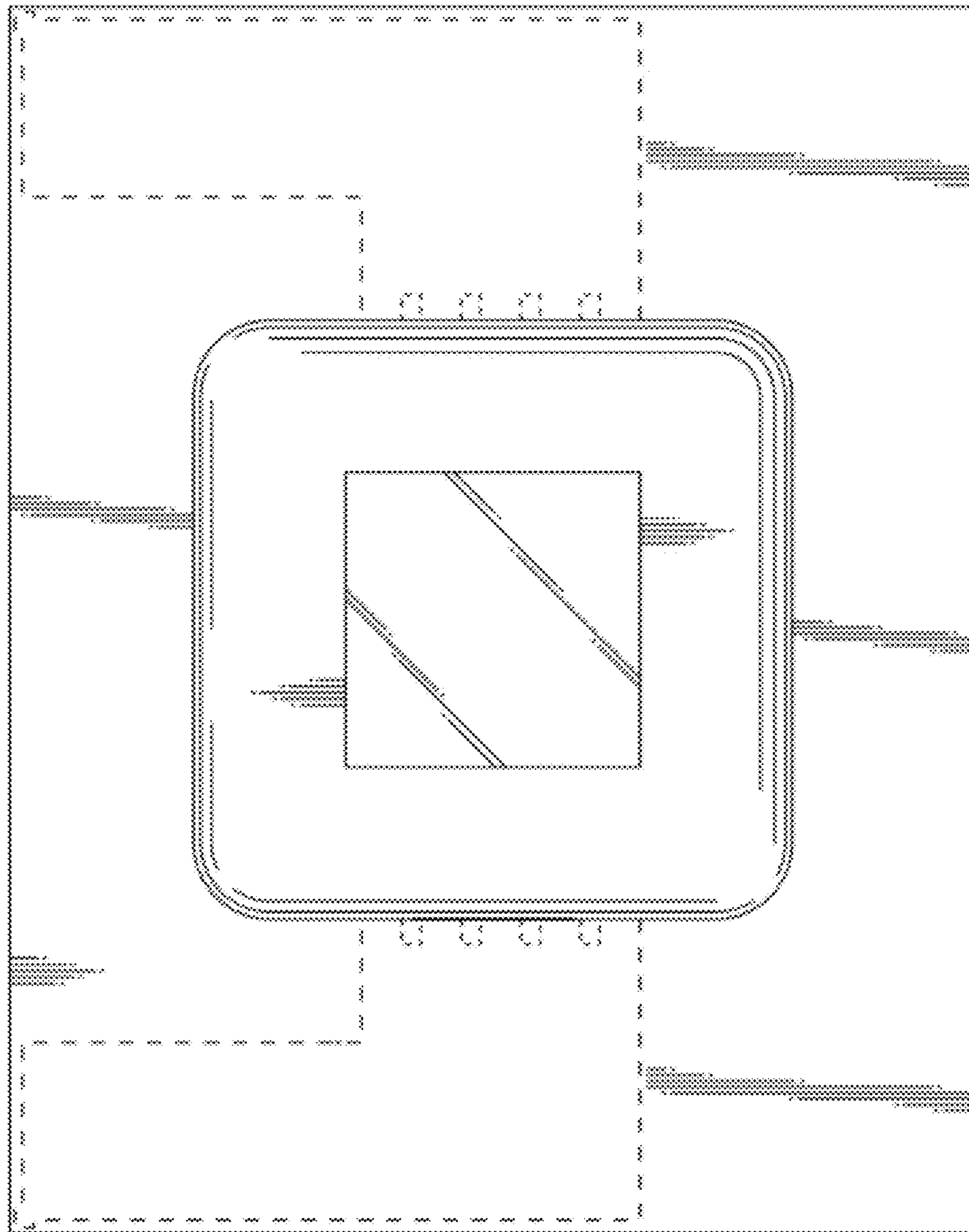


FIG. 9

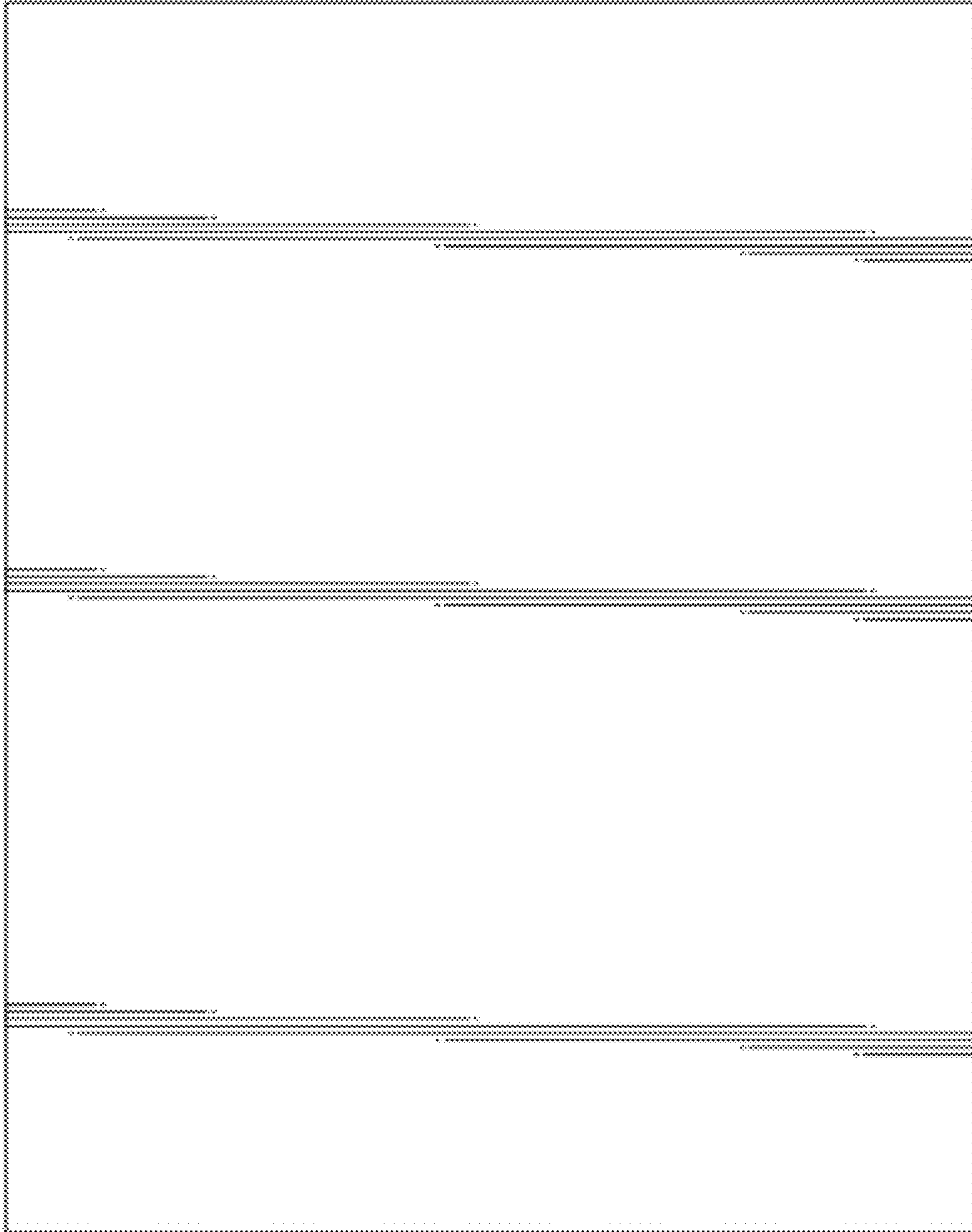


FIG. 10

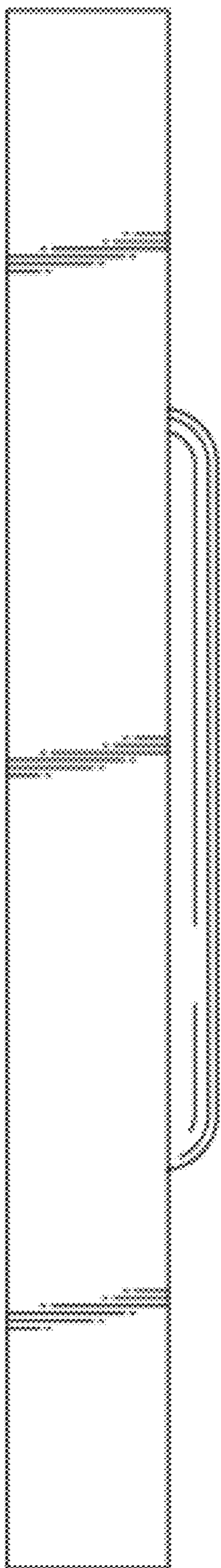


FIG. 11

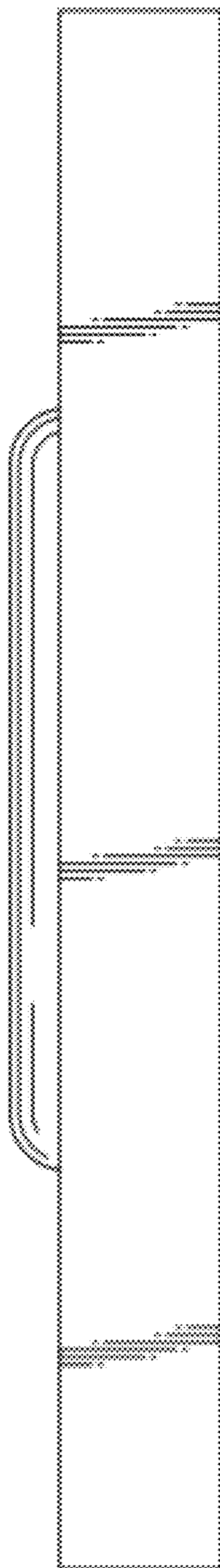


FIG. 12

